



DXT5551

160V NPN TRANSISTOR IN SOT89

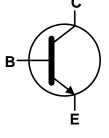
Features

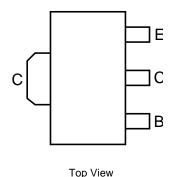
- BV_{CEO} > 160V
- I_C = 600mA High Collector Current
- Complementary PNP Type: DXT5401
- Ideal for Medium Power Switching or Amplification Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.052 grams (Approximate)







Pin-Out

Top View

Device Symbol

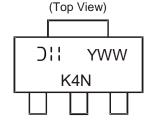
Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXT5551-13	K4N	13	12	2,500

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



☐ → Hanufacturer's Marking

K4N = Product Type Marking Code

YWW = Date Code Marking

Y = Last Digit of Year (ex: 7 = 2017)

WW = Week Code (01 to 52)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	180	V
Collector-Emitter Voltage	V_{CEO}	160	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current	Ic	600	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	D-	0.75	W	
Power Dissipation	(Note 6)	P _D	1.2		
Thermal Resistance, Junction to Ambient Air	(Note 5)	Б	166	°C/W	
Thermal Resistance, Junction to Ambient All	(Note 6)	$R_{ hetaJA}$	104		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

^{5.} For a device mounted with the exposed collector pad on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

^{6.} Same as note 5, except the device is mounted with the exposed collector pad on 25mm x 25mm 1oz copper.

^{7.} Refer to JEDEC specification JESD22-A114 and JESD22-A115.



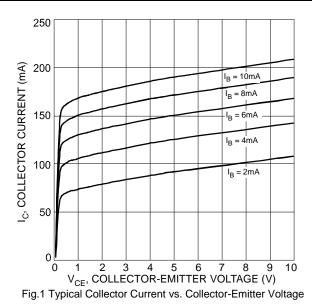
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	180	_	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	160	_	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	6.0	_	_	V	$I_E = 100\mu A$
Collector Cut-off Current		_	-	50	nA	V _{CB} = 120V
Collector Cut-on Current	I _{CBO}			50	μA	V _{CB} = 120V, T _A = +100°C
Emitter Cut-off Current	I _{EBO}	1	_	50	nA	V _{EB} = 4V
ON CHARACTERISTICS (Note 8)						
	h _{FE}	80		_		$I_C = 1$ mA, $V_{CE} = 5$ V
Static Forward Current Transfer Ratio		80	_	250	_	I _C = 10mA, V _{CE} = 5V
		30		_		$I_C = 50 \text{mA}, V_{CE} = 5 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	_	0.15	V	$I_C = 10mA$, $I_B = 1mA$
Collector-Entitler Saturation Voltage				0.20		$I_C = 50\text{mA}, I_B = 5\text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	_	1.0	V	$I_C = 10mA$, $I_B = 1mA$
	V DL(SAT)					$I_C = 50$ mA, $I_B = 5$ mA
SMALL SIGNAL CHARACTERISTICS	_			7		
Transition Frequency	f _T	100	_	300	MHz	$I_C = 10$ mA, $V_{CE} = 10$ V, f = 100MHz
Output Capacitance	C _{obo}	1	_	6	pF	$V_{CB} = 10V, I_E = 0, f = 1MHz$
Small Signal Current Gain	h _{fe}	50	_	200	_	$V_{CB} = 10V$, $I_C = 1mA$, $f = 1kHz$
Noise Figure	NF	_	_	8	dB	$V_{CB} = 5V$, $I_{C} = 200\mu A$,
						$R_S = 1k\Omega$, $f = 1kHz$

Note:

8. Measured under pulsed conditions. Pulse width ≤ 300 µs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



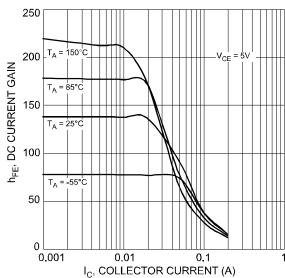
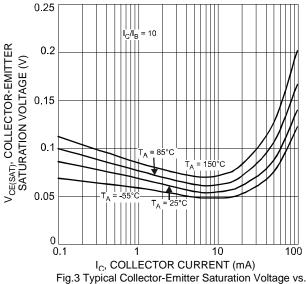


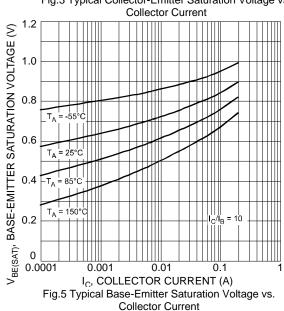
Fig.2 Typical DC Current Gain vs. Collector Current

April 2017

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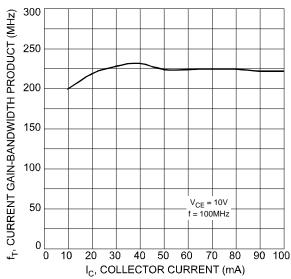


Fig.7 Typical Gain-Bandwidth Product vs. Collector Current

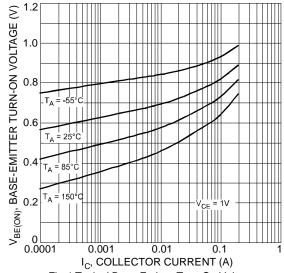


Fig.4 Typical Base-Emitter Turn-On Voltage vs.
Collector Current

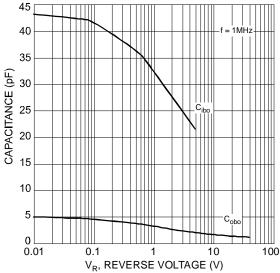


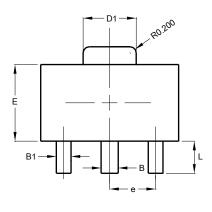
Fig.6 Typical Capacitance Characteristics

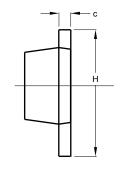


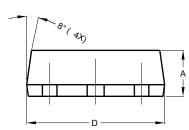
Package Outline Dimensions

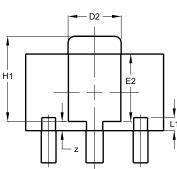
Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89







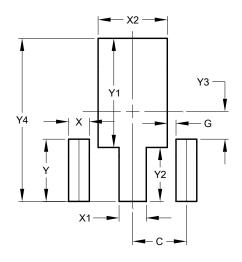


SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
e	-	-	1.50		
Η	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value (in mm)
С	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Υ	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4 530



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